# Quad Freq LVDS+CMOS Oscillator 148.5 / 74.25 / 148.35 / 74.175MHz with 27MHz CMOS

4EA1485A0Z4

# **ADVANCE DATASHEET**

#### **Features**

4 LVDS Frequencies: 148.5, 74.25, 148.35 & 74.175MHz

1 CMOS output: 27MHz
 Frequency Stability: ± 50ppm
 Supply Voltage: 2.5V and 3.3V
 Standard Packages: 7.0 x 5.0 mm

■ RMS phase jitter: <1 ps typical (12k to 20MHz)

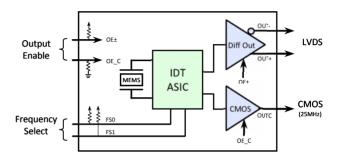
Operating Temperature: - 40 to 85 °C

# 7.0 x 5.0 mm package

#### **General Description**

The 4EA1485A0Z4 is a quad frequency oscillator incorporating IDT's pMEMS technology to generate up to four LVDS clock frequencies. An additional synchronous CMOS output is also provided for general purpose clocking. One 4EA1485A0Z4 can replace up to 5 separate crystal oscillators, reducing inventory and bill-of-material cost. The pinout and footprint is backward compatible to industry standard 7050 size oscillators, ensuring second source compatibility to traditional 6 pin SMD oscillators.

# **Functional Block Diagram**



#### **Pin Description**

Pin	Name	Description	OUTC OE_C
1	OE±	LVDS Output Enable	OE± 1 VDD
6, 7	OUT+, OUT-	LVDS Output	
2	N/C	No connect	N/C OUT-
3,8	GND, VDD	Supply Voltage	]
4, 5	FS0, FS1	Frequency Select	GND OUT+
9	OE_C	CMOS Output Enable	
10	OUTC	CMOS Output	FSO FS1

#### **Frequency Table**

Input*	Output (MHz)			
FS[1,0]	LVDS	CMOS		
1,1	148.50	27.0		
1,0	74.25	27.0		
0,1	148.35	26.973		
0,0	74.175	20.973		

<sup>\*</sup> FS0, FS1 includes weak pull-up resistor

#### Enable/Disable

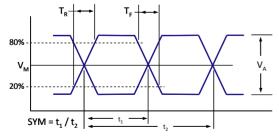
OE±*	LVDS		
HI	ON		
LOW	OFF		

\*Includes weak pull-up resistor

OE_C*	CMOS
HI	ON
LOW	OFF

<sup>\*</sup>Includes weak pull-down resistor

#### **Output Waveform (LVDS)**

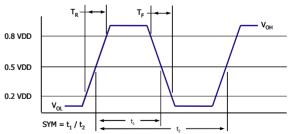


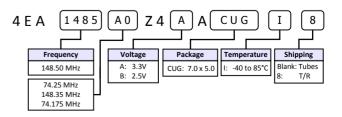
#### **Part Ordering Information**

Package Size	Voltage	Ordering Code	
7.0 x 5.0 mm	3.3V	4EA1485A0Z4AACUGI	
7.0 X 5.0 IIIIII	2.5V	4EA1485A0Z4BACUGI	

<sup>\*</sup> Factory minimum order quantity: 500pcs (T/R)

### **Output Waveform (CMOS)**

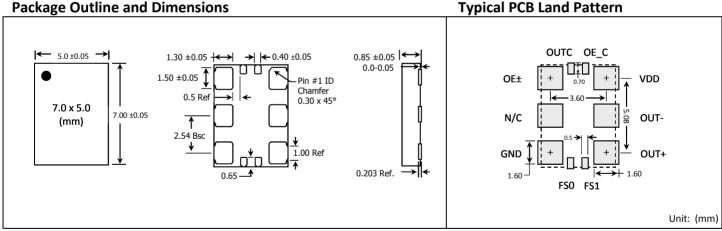




#### **Specification**

	2.5 V			3.3 V		Units	Conditions	
Parameter	Specifications		Specifications					
	Min	Тур	Max	Min	Тур	Max		
Supply Voltage (V <sub>DD</sub> )	2.375	2.50	2.625	2.97	3.30	3.63	V	
Frequency Stability	- 50		+ 50	- 50		+ 50	ppm	Includes supply voltage and temperature variation (-40 to 85°C), reflow drift, and aging.
Supply Current		130			140		mA	No load
Enable/Disable Time			1			1	us	Guaranteed by design
Input HIGH/LOW level	$0.\ 7V_{DD}$		$0.3V_{DD}$	$0.7V_{\text{DD}}$		$0.3V_{DD}$	V	At OE± & OE_C pins
Start-up Time		10			10		ms	Output valid time after power up, 25°C
Aging		± 5			± 5		ppm	25°C, 10 years
						LVD	Outp	ut
Output LOW level		1.05			1.05		V	
Output HIGH level		1.40			1.40		V	
Amplitude (V <sub>A</sub> )		0.35			0.35		V	Single Ended output swing (Pk-Pk)
Mid Level (V <sub>M</sub> )		1.22			1.22		V	
Rise Time (T <sub>R</sub> )		370	420		410	520	ps	Maximum; 20/80% of $V_A$ ; Output load (CL) = 2pF; Guaranteed by Char.
Fall Time (T <sub>F</sub> )		370	420		410	520	ps	Maximum; $20/80\%$ of $V_A$ ; Output load (CL) = 2pF; Guaranteed by Char.
Symmetry (SYM)	48	50	52	48	50	52	%	Worst case; measured at 50% of waveform
Phase Jitter		1.0			0.9		ps	12k to 20MHz, RMS; Measured Differentially
Period Jitter		4.1			4.2		ps	RMS
Cycle-to-Cycle Jitter		32			32		ps	1,000 cycles, Peak
CMOS Output (27 MHz / 26.973 MHz)								
Rise/Fall Time $(T_{R/} T_F)$		500			500		ps	Maximum; 20/80% of V <sub>A</sub> ; Output load (CL) = 15pF
Symmetry (SYM)	48		52	48		52	%	Worst case; measured at 50% of waveform
Output HIGH/LOW level	V <sub>DD</sub> -0.3		0.3	V <sub>DD</sub> -0.3		0.3	V	I <sub>OL</sub> =8mA; I <sub>OH</sub> =-8mA
Period Jitter (rms)		25			20		ps	Measured over 10k cycles
Cycle to Cycle Jitter		120			100		ps	1,000 cycles, Peak

**Package Outline and Dimensions** 





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**Technical Support** 

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